TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

2SK882

FM Tuner, VHF RF Amplifier Applications

Unit: mm

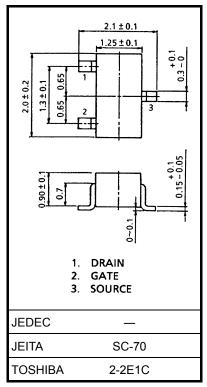
• Low reverse transfer capacitance: $C_{rss} = 0.025 \text{ pF (typ.)}$

Low noise figure: NF = 1.7dB (typ.)
High power gain: G_{ps} = 28dB (typ.)
Recommend operation voltage: 5~15 V

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DS}	20	V
Gate-source voltage	V _{GS}	±5	V
Drain current	ID	30	mA
Drain power dissipation	P _D	100	mW
Channel temperature	T _{ch}	125	°C
Storage temperature	T _{stg}	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



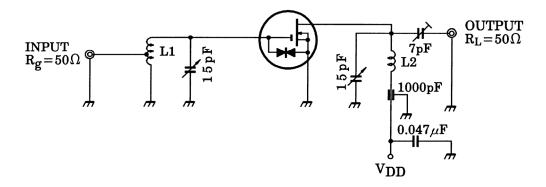
Weight: 0.006 g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I_{GSS}	$V_{DS} = 0, V_{GS} = \pm 5 V$	_	_	±50	nA
Drain-source voltage	V _{DSX}	$V_{GS} = -4 \text{ V}, I_D = 100 \mu\text{A}$	20	_	_	V
Drain current	I _{DSS} (Note)	V _{DS} = 10 V, V _{GS} = 0	3	_	14	mA
Gate-source cut-off voltage	V _{GS (OFF)}	$V_{DS} = 10 \text{ V}, I_D = 100 \mu\text{A}$	_	_	-2.5	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$	_	10		mS
Input capacitance	C _{iss}	V 10 V V 0 f 1 MHz	_	3.0	4.3	pF
Reverse transfer capacitance	C _{rss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	0.025	0.04	pF
Power gain	Gps	V 10 V f 100 MHz (Figure 1)	20	28	_	dB
Noise figure	NF	V _{DS} = 10 V, f = 100 MHz (Figure 1)	_	1.7	3.0	dB

Note: I_{DSS} classification Y: 3.0~7.0 mA, GR: 6.0~14.0 mA



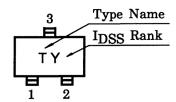
L1: 1.0 mm $_{\varphi}$ silver plated copper wire 4.0 T, 8 mm $_{\varphi}$ ID TAP at 1.0 T from coil end

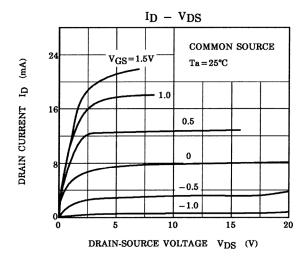
L2: 1.0 mm ϕ silver plated copper wire 3.0 T, 8 mm ϕ ID, 10 mm length

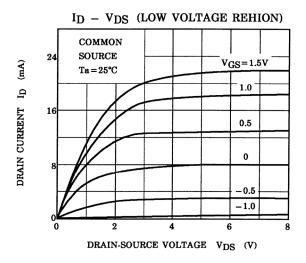
Figure 1 Gps, NF Test Circuit

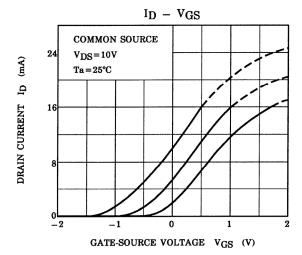
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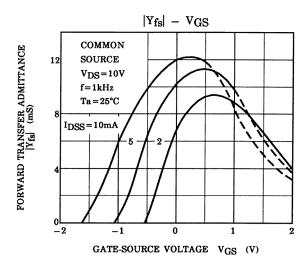
Marking

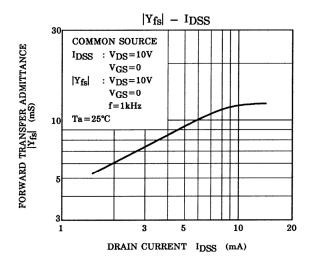


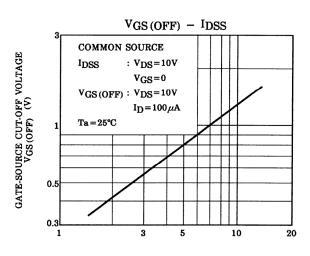




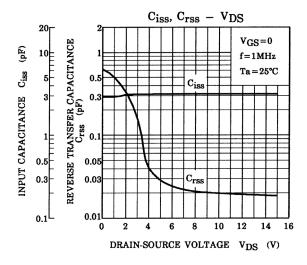


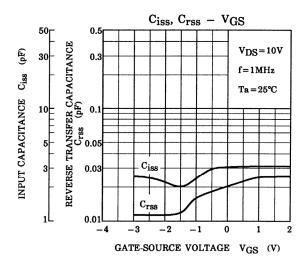


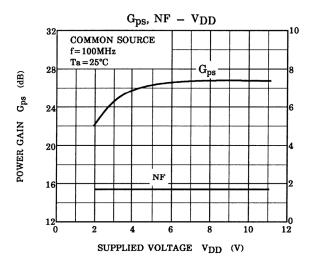


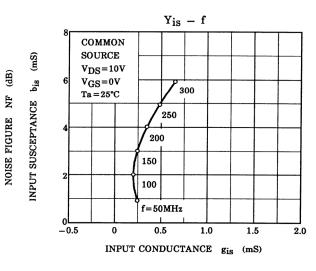


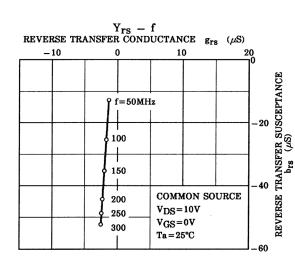
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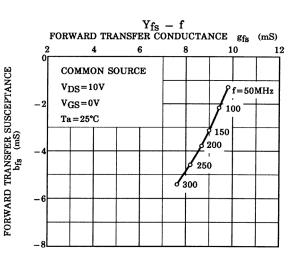


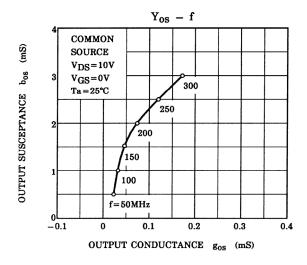


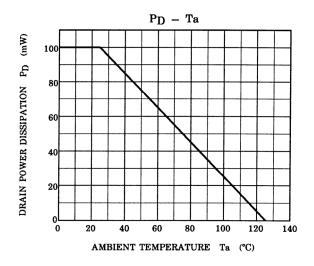












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20070701-EN GENERAL

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